

Product Summary

| BV _{DSS} | R _{DS(ON)} Max | I _D Max T _A = +25°C |
|-------------------|----------------------------|--|
| 60V | 2Ω @ V _{GS} = 10V | 0.3A |
| | 3Ω @ V _{GS} = 5V | 0.2A |

Features and Benefits

- Low On-Resistance: R_{DS(ON)}
- Low Gate Threshold Voltage
- Low Input Capacitance
- Fast Switching Speed
- Low Input/Output Leakage
- ESD Protected Up To 2kV
- **Totally Lead-Free & Fully RoHS Compliant (Notes 1 & 2)**
- **Halogen and Antimony Free. "Green" Device (Note 3)**
- **For automotive applications requiring specific change control (i.e. parts qualified to AEC-Q100/101/200, PPAP capable, and manufactured in IATF 16949 certified facilities), please [contact us](#) or your local Diodes representative.**
<https://www.diodes.com/quality/product-definitions/>

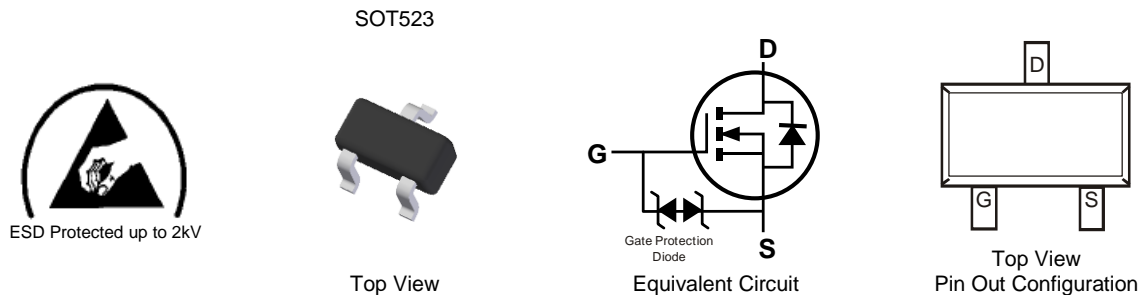
Description and Applications

This MOSFET is designed to minimize the on-state resistance (R_{DS(ON)}), yet maintain superior switching performance, making it ideal for high efficiency power management applications.

- Motor Control
- Power Management Functions

Mechanical Data

- Case: SOT523
- Case Material: Molded Plastic, "Green" Molding Compound. UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminals: Finish – Matte Tin Annealed over Alloy 42 Leadframe. Solderable per MIL-STD-202, Method 208 (Ⓜ3)
- Terminal Connections: See Diagram
- Weight: 0.002 grams (Approximate)

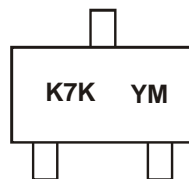


Ordering Information (Note 4)

| Part Number | Case | Packaging |
|-------------|--------|-------------------|
| DMN601TK-7 | SOT523 | 3,000/Tape & Reel |

- Notes:
1. No purposely added lead. Fully EU Directive 2002/95/EC (RoHS), 2011/65/EU (RoHS 2) & 2015/863/EU (RoHS 3) compliant.
 2. See <https://www.diodes.com/quality/lead-free/> for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.
 3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.
 4. For packaging details, go to our website at <https://www.diodes.com/design/support/packaging/diodes-packaging/>.

Marking Information



K7K = Product Type Marking Code
 YM = Date Code Marking
 Y or Ȳ = Year (ex: H = 2020)
 M = Month (ex: 9 = September)

Date Code Key

| Year | 2005 | ... | 2020 | 2021 | 2022 | 2023 | 2024 | 2025 | 2026 | 2027 | 2028 | 2029 |
|------|------|-----|------|------|------|------|------|------|------|------|------|------|
| Code | S | ... | H | I | J | K | L | M | N | O | P | R |

| Month | Jan | Feb | Mar | Apr | May | Jun | Jul | Aug | Sep | Oct | Nov | Dec |
|-------|-----|-----|-----|-----|-----|-----|-----|-----|-----|-----|-----|-----|
| Code | 1 | 2 | 3 | 4 | 5 | 6 | 7 | 8 | 9 | O | N | D |

Maximum Ratings (@T_A = +25°C, unless otherwise specified.)

| Characteristic | Symbol | Value | Unit |
|------------------------|------------------|-----------------|------|
| Drain-Source Voltage | V _{DSS} | 60 | V |
| Gate-Source Voltage | V _{GSS} | ±20 | V |
| Drain Current (Note 5) | I _D | Continuous | 300 |
| | | Pulsed (Note 6) | 800 |

Thermal Characteristics (@T_A = +25°C, unless otherwise specified.)

| Characteristic | Symbol | Value | Unit |
|---|-----------------------------------|-------------|------|
| Total Power Dissipation (Note 5) | P _D | 150 | mW |
| Thermal Resistance, Junction to Ambient | R _{θJA} | 833 | °C/W |
| Operating and Storage Temperature Range | T _J , T _{STG} | -65 to +150 | °C |

Electrical Characteristics (@T_A = +25°C unless otherwise specified.)

| Characteristic | Symbol | Min | Typ | Max | Unit | Test Condition |
|---|---------------------|-----|------|-----|------|---|
| OFF CHARACTERISTICS (Note 7) | | | | | | |
| Drain-Source Breakdown Voltage | BV _{DSS} | 60 | — | — | V | V _{GS} = 0V, I _D = 10μA |
| Zero Gate Voltage Drain Current | I _{DSS} | — | — | 1.0 | μA | V _{DS} = 60V, V _{GS} = 0V |
| Gate-Source Leakage | I _{GSS} | — | — | ±10 | μA | V _{GS} = ±20V, V _{DS} = 0V |
| ON CHARACTERISTICS (Note 7) | | | | | | |
| Gate Threshold Voltage | V _{GS(TH)} | 1.0 | 1.6 | 2.5 | V | V _{DS} = 10V, I _D = 1mA |
| Static Drain-Source On-Resistance | R _{DS(ON)} | — | 1.3 | 2.0 | Ω | V _{GS} = 10V, I _D = 0.5A |
| | | — | 1.4 | 3.0 | | |
| Forward Transfer Admittance | Y _{FS} | 80 | — | — | ms | V _{DS} = 10V, I _D = 0.2A |
| DYNAMIC CHARACTERISTICS (Note 8) | | | | | | |
| Input Capacitance | C _{iss} | — | — | 50 | pF | V _{DS} = 25V, V _{GS} = 0V f = 1.0MHz |
| Output Capacitance | C _{oss} | — | — | 25 | pF | |
| Reverse Transfer Capacitance | C _{rss} | — | — | 5.0 | pF | |
| Turn-On Delay Time | t _{D(ON)} | — | 3.4 | — | ns | V _{DD} = 25V, V _{GS} = 10V, R _G = 25Ω, I _D = 500mA |
| Turn-On Rise Time | t _R | — | 2.4 | — | ns | |
| Turn-Off Delay Time | t _{D(OFF)} | — | 11.0 | — | ns | |
| Turn-Off Fall Time | t _F | — | 4.9 | — | ns | |

- Notes:
5. Device mounted on FR-4 PCB.
 6. Pulse width ≤10μs, Duty Cycle ≤1%.
 7. Short duration pulse test used to minimize self-heating effect.
 8. Guaranteed by design. Not subject to product testing.

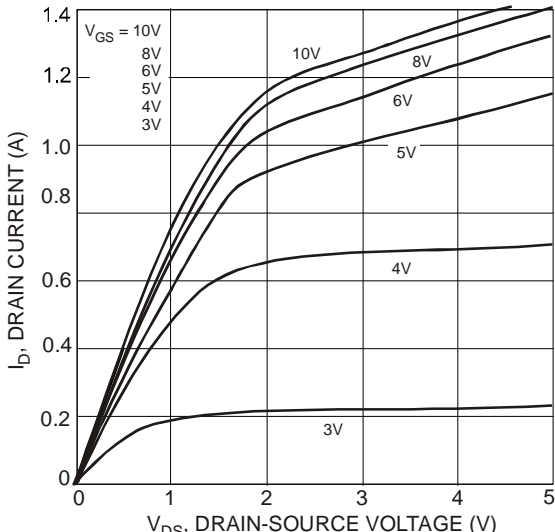


Fig. 1 Typical Output Characteristics

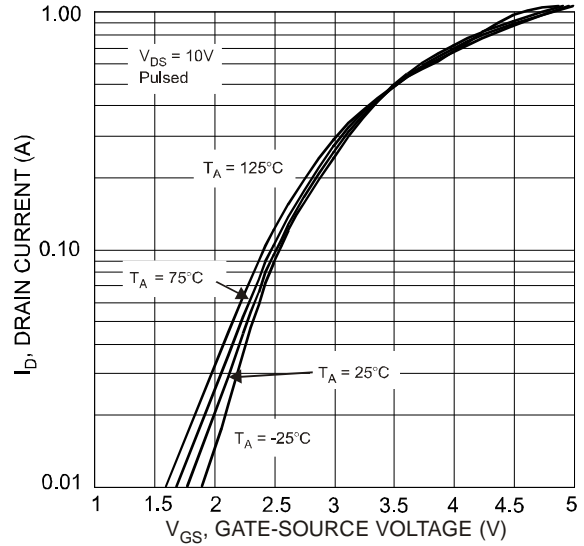


Fig. 2 Typical Transfer Characteristics

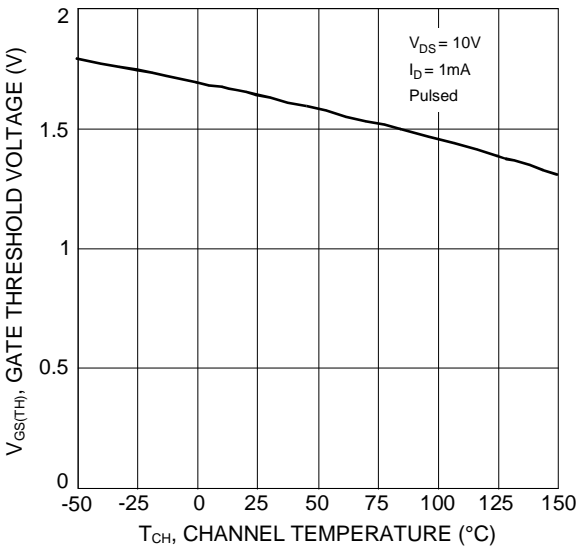


Fig. 3 Gate Threshold Voltage vs. Channel Temperature

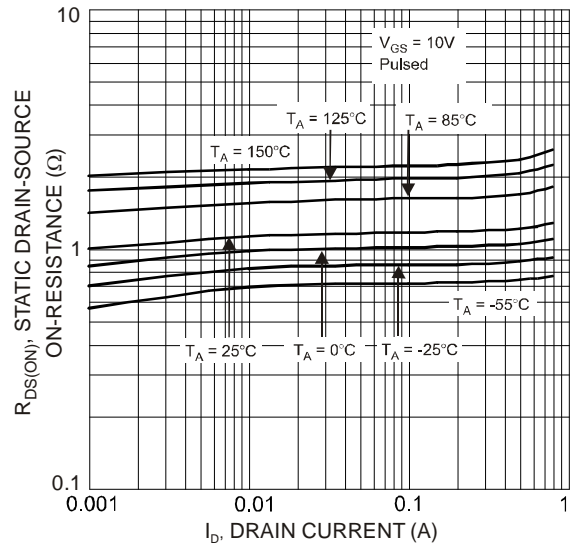


Fig. 4 Static Drain-Source On-Resistance vs. Drain Current

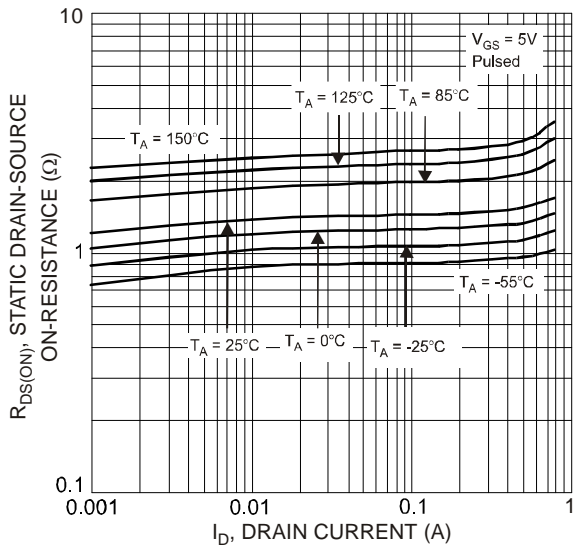


Fig. 5 Static Drain-Source On-Resistance vs. Drain Current

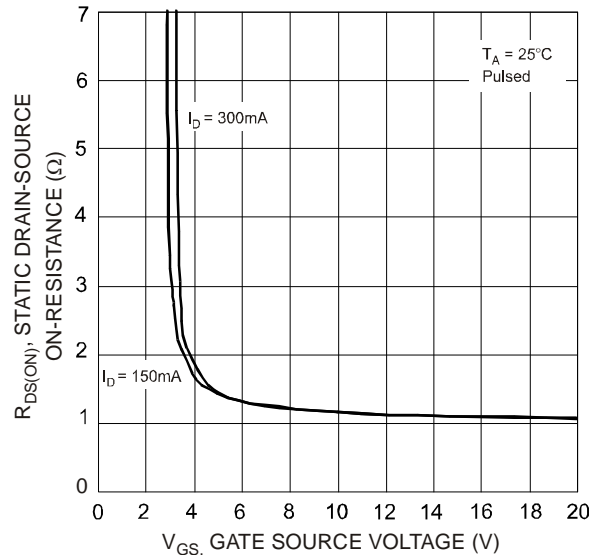


Fig. 6 Static Drain-Source On-Resistance vs. Gate-Source Voltage

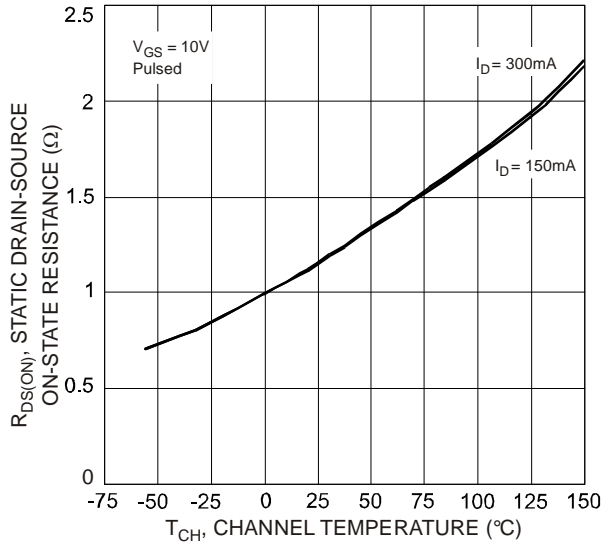


Fig. 7 Static Drain-Source On-State Resistance vs. Channel Temperature

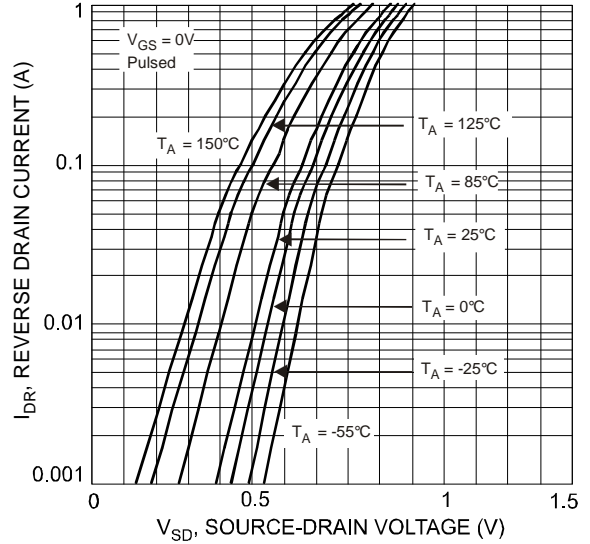


Fig. 8 Reverse Drain Current vs. Source-Drain Voltage

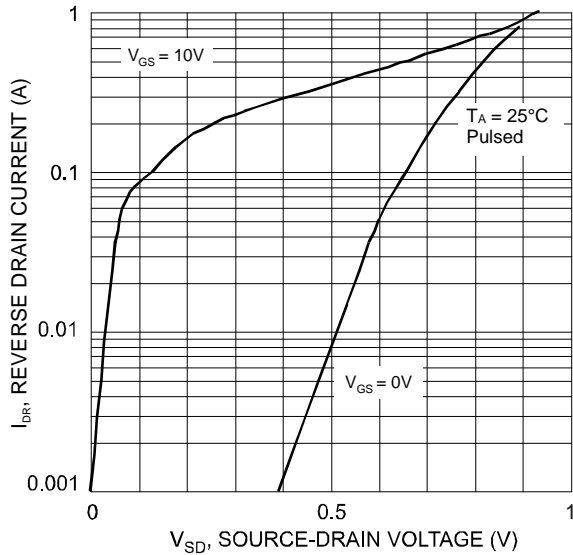


Fig. 9 Reverse Drain Current vs. Source-Drain Voltage

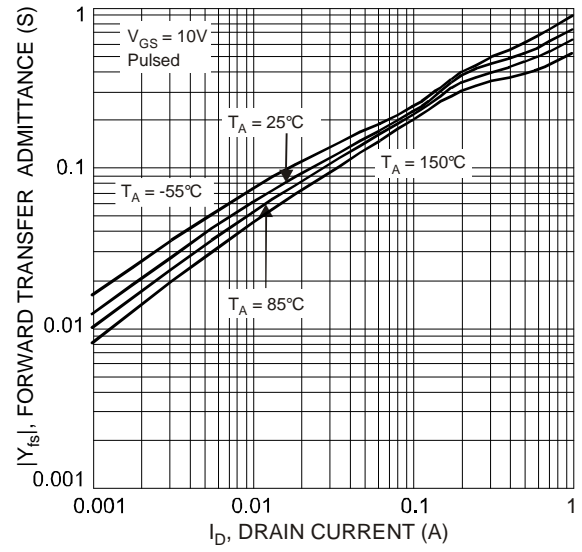
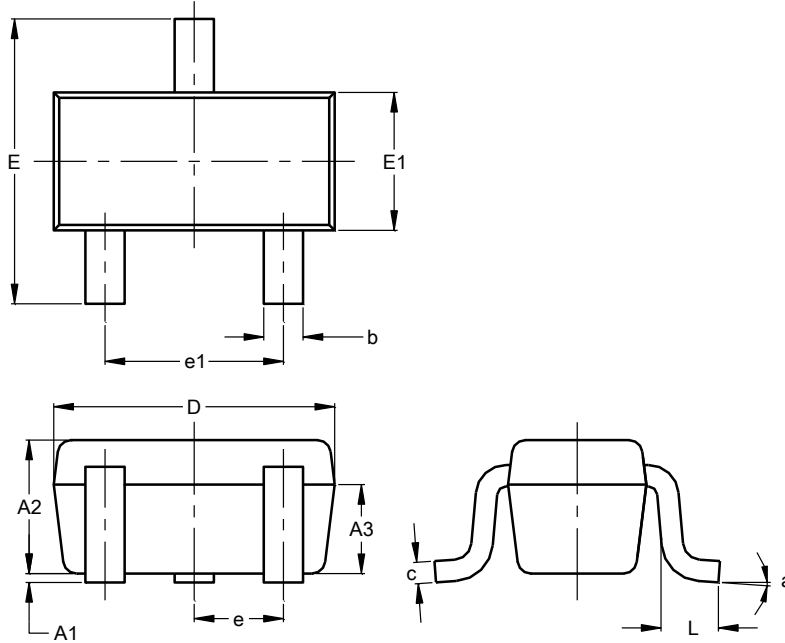


Fig. 10 Forward Transfer Admittance vs. Drain Current

Package Outline Dimensions

Please see <http://www.diodes.com/package-outlines.html> for the latest version.

SOT523

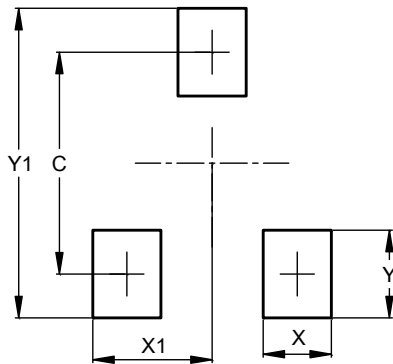


| SOT523 | | | |
|----------------------|----------|------|------|
| Dim | Min | Max | Typ |
| A1 | 0.00 | 0.10 | 0.05 |
| A2 | 0.60 | 0.80 | 0.75 |
| A3 | 0.45 | 0.65 | 0.50 |
| b | 0.15 | 0.30 | 0.22 |
| c | 0.10 | 0.20 | 0.12 |
| D | 1.50 | 1.70 | 1.60 |
| E | 1.45 | 1.75 | 1.60 |
| E1 | 0.75 | 0.85 | 0.80 |
| e | 0.50 BSC | | |
| e1 | 0.90 | 1.10 | 1.00 |
| L | 0.20 | 0.40 | 0.33 |
| a | 0° | -- | 8° |
| All Dimensions in mm | | | |

Suggested Pad Layout

Please see <http://www.diodes.com/package-outlines.html> for the latest version.

SOT523



| Dimensions | Value (in mm) |
|------------|---------------|
| C | 1.29 |
| X | 0.40 |
| X1 | 0.70 |
| Y | 0.51 |
| Y1 | 1.80 |

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